



Product Change Notice

Micron PCN: 31185
 Date: 3/5/2014

Type of Change:	Manufacturing Site Change	
Title of Change:	512Mb 50nm DDR1 (T67A) and DDR2 (U67A) Fab Site Transition (from Singapore to Virginia, USA)	
Description of Change:	Fabrication of Micron's 50nm 512Mb DDR1 (T67A) and DDR2 (U67A) parts will move from Singapore (Fab 7) to Virginia, USA (Fab 6).	
Reason for Change:	Optimization of Manufacturing Efficiency	
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Product Affected: All T67A and U67A parts

Affected Micron Part Number

MT46V32M16CV-5B AIT:J	MT46V32M16P-5B XIT:J	MT47H32M16HR-25E AIT:G
MT46V32M16CY-5B AAT:J	MT46V32M16T67A3WC1	MT47H32M16HR-25E V:G
MT46V32M16CY-5B AIT:J	MT46V64M8CY-5B AIT:J	MT47H32M16HW-25E AAT:G
MT46V32M16CY-5B X:J	MT46V64M8CY-5B X:J	MT47H32M16HW-25E AIT:G
MT46V32M16CY-5B XIT:J	MT46V64M8P-5B AIT:J	MT47H64M8CF-25E AIT:G
MT46V32M16P-5B AIT:J	MT47H32M16HR-25E AAT:G	

Method of Identification:

Component Mark: The first character in the "country of diffusion-encapsulation" code in the component mark for product fabricated will change from "2" (Singapore) to "1" (USA). Please refer to Micron Customer Service Note-11 for detailed description of marking codes

Micron Sites Affected:	Micron Manassas (MTV), Micron Singapore(Tech)
Sample Available:	Now
Qual Data Available:	Now
Product Ship Date:	May 2014